Retriggerable Monostable Multivibrators

These dc triggered multivibrators feature pulse width control by three methods. The basic pulse width is programmed by selection of external resistance and capacitance values. The LS122 has an internal timing resistor that allows the circuits to be used with only an external capacitor. Once triggered, the basic pulse width may be extended by retriggering the gated low-level-active (A) or high-level-active (B) inputs, or be reduced by use of the overriding clear.

- Overriding Clear Terminates Output Pulse
- Compensated for V_{CC} and Temperature Variations
- DC Triggered from Active-High or Active-Low Gated Logic Inputs
- Retriggerable for Very Long Output Pulses, up to 100% Duty Cycle
- Internal Timing Resistors on LS122



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http://onsemi.com

LOW POWER SCHOTTKY



| ORDERING INFORMATION | | | | | | | |
|----------------------|------------|------------------|--|--|--|--|--|
| Device | Package | Shipping | | | | | |
| SN74LS122N | 14 Pin DIP | 2000 Units/Box | | | | | |
| SN74LS122D | SOIC-14 | 55 Units/Rail | | | | | |
| SN74LS122DR2 | SOIC-14 | 2500/Tape & Reel | | | | | |
| SN74LS123N | 16 Pin DIP | 2000 Units/Box | | | | | |
| SN74LS123D | SOIC-16 | 38 Units/Rail | | | | | |
| SN74LS123DR2 | SOIC-16 | 2500/Tape & Reel | | | | | |
| SN74LS123M | SOEIAJ-16 | See Note 1 | | | | | |
| SN74LS123MEL | SOEIAJ-16 | See Note 1 | | | | | |

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

GUARANTEED OPERATING RANGES

| Symbol | Parameter | Min | Тур | Max | Unit |
|------------------------------------|--|----------------|-----|------|------|
| VCC | Supply Voltage | 4.75 | 5.0 | 5.25 | V |
| Т _А | Operating Ambient Temperature Range | 0 | 25 | 70 | °C |
| ЮН | Output Current – High |) | | -0.4 | mA |
| IOL | Output Current – Low | | | 8.0 | mA |
| R _{ext} | External Timing Resistance | 5.0 | | 260 | kΩ |
| C _{ext} | External Capacitance | No Restriction | | | |
| R _{ext} /C _{ext} | Wiring Capacitance at R _{ext} /C _{ext} Terminal | | | 50 | pF |



 $\rm NC-NO$ INTERNAL CONNECTION.

NOTES:

1. An external timing capacitor may be connected between C_{ext} and R_{ext}/C_{ext} (positive).

2. To use the internal timing resistor of the LS122, connect R_{int} to $\mathsf{V}_{CC}.$

3. For improved pulse width accuracy connect an external resistor between Rext/Cext and V_{CC} with Rint open-circuited.

4. To obtain variable pulse widths, connect an external variable resistance between R_{int}/C_{ext} and V_{CC} .

LS122 FUNCTIONAL TABLE

| | INPUTS | | | | | | |
|------------|--------------|--------------|------------|------------|---|---|--|
| CLEAR | A1 | A2 | B1 | B2 | Q | Q | |
| L | Х | Х | Х | Х | L | Н | |
| Х | н | Н | Х | Х | L | Н | |
| Х | Х | Х | L | Х | L | Н | |
| Х | Х | Х | Х | L | L | Н | |
| Н | L | Х | \uparrow | н | л | ъ | |
| Н | L | Х | н | \uparrow | л | ъ | |
| Н | Х | L | \uparrow | н | л | ъ | |
| Н | Х | L | н | \uparrow | л | ប | |
| Н | н | \downarrow | н | н | л | U | |
| Н | \downarrow | \downarrow | н | н | л | ъ | |
| Н | \downarrow | Н | н | Н | л | ъ | |
| \uparrow | L | Х | н | Н | л | υ | |
| \uparrow | Х | L | Н | Н | л | ъ | |

TYPICAL APPLICATION DATA

The output pulse t_W is a function of the external components, C_{ext} and R_{ext} or C_{ext} and R_{int} on the LS122. For values of $C_{ext} \ge 1000$ pF, the output pulse at $V_{CC} = 5.0$ V and $V_{RC} = 5.0$ V (see Figures 1, 2, and 3) is given by

 $t_W = K R_{ext} C_{ext}$ where K is nominally 0.45

If C_{ext} is on pF and R_{ext} is in k Ω then tW is in nanoseconds.

The C_{ext} terminal of the LS122 and LS123 is an internal connection to ground, however for the best system performance C_{ext} should be hard-wired to ground.

Care should be taken to keep R_{ext} and C_{ext} as close to the monostable as possible with a minimum amount of inductance between the R_{ext}/C_{ext} junction and the R_{ext}/C_{ext} pin. Good groundplane and adequate bypassing should be designed into the system for optimum performance to ensure that no false triggering occurs.

It should be noted that the C_{ext} pin is internally connected to ground on the LS122 and LS123, but not on the LS221. Therefore, if C_{ext} is hard-wired externally to ground, substitution of a LS221 onto a LS123 socket will cause the LS221 to become non-functional.

The switching diode is not needed for electrolytic capacitance application and should not be used on the LS122 and LS123.

To find the value of K for $C_{ext} \ge 1000$ pF, refer to Figure 4. Variations on V_{CC} or V_{RC} can cause the value of K to change, as can the temperature of the LS123, LS122.

LS123 FUNCTIONAL TABLE

| IN | OUT | PUTS | | |
|----------|--------------|------------|---|---|
| CLEAR | Α | В | Q | Q |
| L | Х | Х | L | Н |
| Х | н | Х | L | н |
| Х | Х | L | L | н |
| н | L | \uparrow | л | പ |
| н | \downarrow | Н | л | ъ |
| <u>↑</u> | L | Н | л | ഹ |

Figures 5 and 6 show the behavior of the circuit shown in Figures 1 and 2 if separate power supplies are used for V_{CC} and V_{RC} . If V_{CC} is tied to V_{RC} , Figure 7 shows how K will vary with V_{CC} and temperature. Remember, the changes in R_{ext} and C_{ext} with temperature are not calculated and included in the graph.

As long as $C_{ext} \ge 1000 \text{ pF}$ and $5K \le R_{ext} \le 260K$, the change in K with respect to R_{ext} is negligible.

If $C_{ext} \le 1000 \text{ pF}$ the graph shown on Figure 8 can be used to determine the output pulse width. Figure 9 shows how K will change for $C_{ext} \le 1000 \text{ pF}$ if V_{CC} and V_{RC} are connected to the same power supply. The pulse width tw in nanoseconds is approximated by

$t_W = 6 + 0.05 C_{ext} (pF) + 0.45 R_{ext} (k\Omega) C_{ext} + 11.6 R_{ext}$

In order to trim the output pulse width, it is necessary to include a variable resistor between V_{CC} and the R_{ext}/C_{ext} pin or between V_{CC} and the R_{ext} pin of the LS122. Figure 10, 11, and 12 show how this can be done. R_{ext} remote should be kept as close to the monostable as possible.

Retriggering of the part, as shown in Figure 3, must not occur before C_{ext} is discharged or the retrigger pulse will not have any effect. The discharge time of C_{ext} in nanoseconds is guaranteed to be less than 0.22 C_{ext} (pF) and is typically 0.05 C_{ext} (pF).

For the smallest possible deviation in output pulse widths from various devices, it is suggested that C_{ext} be kept $\geq 1000 \text{ pF}.$

WAVEFORMS



OVERRIDING THE OUTPUT PULSE

| | | | | Limits | | | | |
|-----------------|-------------------------------|--------------------|-----|--------|------|------|--|-------------------------------------|
| Symbol | Parameter | | Min | Тур | Max | Unit | Test C | onditions |
| VIH | Input HIGH Voltage | | 2.0 | | | V | Guaranteed Input HIGH Voltage for All Inputs | |
| VIL | Input LOW Voltage | | | | 0.8 | V | Guaranteed Input LOW Voltage fo All Inputs | |
| VIK | Input Clamp Diode Voltage | | | -0.65 | -1.5 | V | $V_{CC} = MIN, I_{IN}$ | = -18 mA |
| VOH | Output HIGH Voltage | utput HIGH Voltage | | 3.5 | | V | V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table | |
| | | | | 0.25 | 0.4 | V | I _{OL} = 4.0 mA | $V_{CC} = V_{CC} MIN,$ |
| VOL | Output LOW Voltage | | | 0.35 | 0.5 | V | I _{OL} = 8.0 mA | vIN = vIL or vIH per Truth Table |
| 1 | | | | | 20 | μA | V _{CC} = MAX, V _I | N = 2.7 V |
| ЧН | input high Current | | | | 0.1 | mA | V _{CC} = MAX, V _I | N = 7.0 V |
| ۱ _{IL} | Input LOW Current | | | | -0.4 | mA | V _{CC} = MAX, V _{IN} = 0.4 V | |
| IOS | Short Circuit Current (Note 2 | 2) | -20 | | -100 | mA | V _{CC} = MAX | |
| | Power Supply Current | LS122 | | | 11 | m^ | | |
| 'CC | | LS123 | | | 20 | IIIA | vCC = WAX | |

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

2. Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

| | | | Limits | | | | |
|-------------------|--|-----|--------|-----|------|---|--|
| Symbol | Parameter | Min | Тур | Max | Unit | Test Conditions | |
| ^t PLH | Propagation Delay, A to \underline{Q} | | 23 | 33 | | | |
| ^t PHL | Propagation Delay, A to Q | | 32 | 45 | ns | Cext = 0 | |
| ^t PLH | Propagation Delay, B to \underline{Q} | | 23 | 44 | | $C_L = 15 \text{pF}$ | |
| ^t PHL | Propagation Delay, B to Q | | 34 | 56 | ns | R _{ext} = 5.0 kΩ | |
| ^t PI H | Propagation Delay, Clear to \overline{Q} | | 28 | 45 | | $R_L = 2.0 \text{ k}\Omega$ | |
| tPHL | Propagation Delay, Clear to Q | | 20 | 27 | ns | | |
| tW min | A or B to Q | | 116 | 200 | ns | C _{ext} = 1000 pF, R _{ext} = 10 kΩ, | |
| t _W Q | A to B to Q | 4.0 | 4.5 | 5.0 | μs | $C_{L} = 15 \text{ pF}, R_{L} = 2.0 \text{ k}\Omega$ | |

AC SETUP REQUIREMENTS (T_A = 25°C, V_{CC} = 5.0 V)

| | | Limits | | | | |
|--------|-------------|--------|-----|-----|------|-----------------|
| Symbol | Parameter | Min | Тур | Max | Unit | Test Conditions |
| tW | Pulse Width | 40 | | | ns | |













Figure 4.





Figure 8.











Figure 11. LS122 Remote Trimming Circuit Without Rext





PACKAGE DIMENSIONS



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL
- DIMEDSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

| | INC | HES | MILLIN | IFTERS |
|-----|-------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.715 | 0.770 | 18.16 | 18.80 |
| В | 0.240 | 0.260 | 6.10 | 6.60 |
| С | 0.145 | 0.185 | 3.69 | 4.69 |
| D | 0.015 | 0.021 | 0.38 | 0.53 |
| F | 0.040 | 0.070 | 1.02 | 1.78 |
| G | 0.100 | BSC | 2.54 BSC | |
| н | 0.052 | 0.095 | 1.32 | 2.41 |
| J | 0.008 | 0.015 | 0.20 | 0.38 |
| K | 0.115 | 0.135 | 2.92 | 3.43 |
| L | 0.290 | 0.310 | 7.37 | 7.87 |
| М | | 10° | | 10° |
| N | 0.015 | 0.039 | 0.38 | 1.01 |

D SUFFIX PLASTIC SOIC PACKAGE CASE 751A-03 ISSUE F



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIN | IETERS | INC | HES |
|-----|--------|--------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 8.55 | 8.75 | 0.337 | 0.344 |
| В | 3.80 | 4.00 | 0.150 | 0.157 |
| С | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 | BSC | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| К | 0.10 | 0.25 | 0.004 | 0.009 |
| М | 0 ° | 7° | 0 ° | 7° |
| Р | 5.80 | 6.20 | 0.228 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

2.

3.

DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 ROUNDED CORNERS OPTIONAL.

| | INC | HES | MILLIN | ETERS | |
|-----|-------|-------|----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.740 | 0.770 | 18.80 | 19.55 | |
| В | 0.250 | 0.270 | 6.35 | 6.85 | |
| С | 0.145 | 0.175 | 3.69 | 4.44 | |
| D | 0.015 | 0.021 | 0.39 | 0.53 | |
| F | 0.040 | 0.70 | 1.02 | 1.77 | |
| G | 0.100 | BSC | 2.54 BSC | | |
| Н | 0.050 | BSC | 1.27 BSC | | |
| ſ | 0.008 | 0.015 | 0.21 | 0.38 | |
| ĸ | 0.110 | 0.130 | 2.80 | 3.30 | |
| L | 0.295 | 0.305 | 7.50 | 7.74 | |
| М | 0 ° | 10 ° | 0 ° | 10 ° | |
| S | 0.020 | 0.040 | 0.51 | 1.01 | |

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 **ISSUE J**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.
- 3.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 4.
- PER SIDE. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION. 5.

| | MILLIN | IETERS | INC | HES | |
|-----|--------|--------|-----------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 9.80 | 10.00 | 0.386 | 0.393 | |
| В | 3.80 | 4.00 | 0.150 | 0.157 | |
| С | 1.35 | 1.75 | 0.054 | 0.068 | |
| D | 0.35 | 0.49 | 0.014 | 0.019 | |
| F | 0.40 | 1.25 | 0.016 | 0.049 | |
| G | 1.27 | BSC | 0.050 BSC | | |
| J | 0.19 | 0.25 | 0.008 | 0.009 | |
| K | 0.10 | 0.25 | 0.004 | 0.009 | |
| Μ | 0 ° | 7° | 0 ° | 7° | |
| Ρ | 5.80 | 6.20 | 0.229 | 0.244 | |
| B | 0.25 | 0.50 | 0.010 | 0.019 | |

PACKAGE DIMENSIONS

M SUFFIX SOEIAJ PACKAGE CASE 966-01 ISSUE O



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0.10 (0.004)





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2
- CONTROLLING DIMENSION: MILLIMETER. DIMENSIONS D AND E DO NOT INCLUDE MOLD 3. FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006)
- PER SIDE TERMINAL NUMBERS ARE SHOWN FOR 4.
- REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT 5. INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0 46 (0 018)

| | MILLIN | IETERS | INC | HES |
|----------------|--------|--------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | | 2.05 | | 0.081 |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| С | 0.18 | 0.27 | 0.007 | 0.011 |
| D | 9.90 | 10.50 | 0.390 | 0.413 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| е | 1.27 | BSC | 0.050 BSC | |
| HE | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| LE | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0 ° | 10 ° | 0 ° | 10 ° |
| Q ₁ | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | | 0.78 | | 0.031 |

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